Supporting Information

Black Rutile of (Sn,Ti)O₂ initializing electrochemically Reversible Sn Nanodots Embedded in Amorphous Lithiated Titania Matrix for Efficient Lithium Storage

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Theoretical Section

Calculations have been performed within the framework of density functional theory (DFT) as implemented by the Vienna an initio Simulation Package (VASP).^[S1,S2] The exchange-correlation energy is treated in the generalized-gradient approximation (GGA) using Perdew-Burke-Ernzerhof (PBE) functional.^[S3] The model was constructed on the 1×1 (101) surface (30 atomic layer) with a 20 Å vacuum layer. Here, the cutoff energy of plane wave was chosen at 450 eV. For the structure optimizations, $7 \times 7 \times 1$ Monkhorst-Pack (MP) grids were used. The changes in total energies between two successive electronic steps are less than 10-5 eV, meanwhile, all the Hellmann-Feynman force acting on each atoms was lower than 0.05 eV /Å.

(Sn,Ti)O2-based systems	Elemental ratio	Long cycles@0.2 A g ⁻¹ (mA h g ⁻¹)	High rate capacity (mA h g ⁻¹)	References
Black (Sn,Ti)O ₂	80 at% Sn	583 (100 cycles)	335 (5 A g ⁻¹)	Our work
SnO_2 nanoflakes on TiO_2 nanotubes	80 at% Sn	530 (50 cycles)	358 (3.2 A g ⁻¹)	2014 [S4]
SnO ₂ @TiO ₂ double shell nanotubes	48 at% Sn	300 (50 cycles)	200 (1.5 A g ⁻¹)	2013 [S5]
(Sn,Ti)O ₂ solid solution nanorods	20 at% Sn	300 (50 cycles)	217 (3 A g ⁻¹)	2013 [S6]
Ordered network of interconnected SnO ₂	100 at% Sn	564 (100 cycles)	300 (4.7 A g ⁻¹)	2015 [S7]
Black anatase titania	100 at% Ti	188 (100 cycles)	158 (5 A g ⁻¹)	2013 [S8]

Table S1. Comparison of capacity retention and high rate performance for (Sn,Ti)O₂ based anodes.

 Table S2 Lattice parameters of the samples with different stoichiometric.

Sample	2-Theta(110)	d ₍₁₁₀₎ -calculated	d ₍₁₁₀₎ -theoretical
B-SnO ₂	26.611	3.347	3.347
$B-S_{0.8}T_{0.2}O_2$	26.790	3.325	3.327
$B-S_{0.6}T_{0.4}O_2$	26.964	3.304	3.307
Rutile-TiO ₂	27.446		3.247

Table S3 Comparison of the detail data of equivalent circuit for $(Sn,Ti)O_2$ based anodes.

Sample	R _s	R _{ct}	W-R	W-T	W-P	CPE-P	CPE-T
B-STO ₂	3.89	90.1	119.9	0.9479	0.4497	0.7461	2.761*10 ⁻⁵
W-STO ₂	4.2	192.0	171.9	1.409	0.4488	0.7927	1.536*10-5



Figure S1. XRD characterization of the samples with different stoichiometric (a), partial magnifications of the region showing the shift of peak positions (b), and samples after hydrogen plasma reduction at 500 °C.



Figure S2. The TEM of air annealed W-STO₂.



Figure S3. Elemental mapping images of B-STO₂ of oxygen, titanium, and stannum.



Figure S4. The Raman spectra of air annealed W-STO₂, and B-STO₂ after hydrogen plasma reduction.



Figure S5. The XPS spectra of hydrogen plasma reduced B-STO₂.



Figure S6. Schematic of the structure of B-STO₂.



Figure S7. Galvanostatic charge/discharge curves of the 1st, 2nd, 20th, and 100th cycle of the B-STO₂ electrode.



Figure S8. Sn 3d spectra and Ti 2p spectra of B-STO₂ after discharging.

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